## NSN 5962-01-213-4588

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View Online at https://aerobasegroup.com/nsn/5962-01-213-4588 **Body Length:** 1.220 inches **Body Width:** 0.520 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** +55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** An/wsc- (v) 9 **Features Provided:** Hermetically sealed and programmable and w/enable and static operation **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** Err-060 hand pull and err-060 hand **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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